

## **Supporting Information**

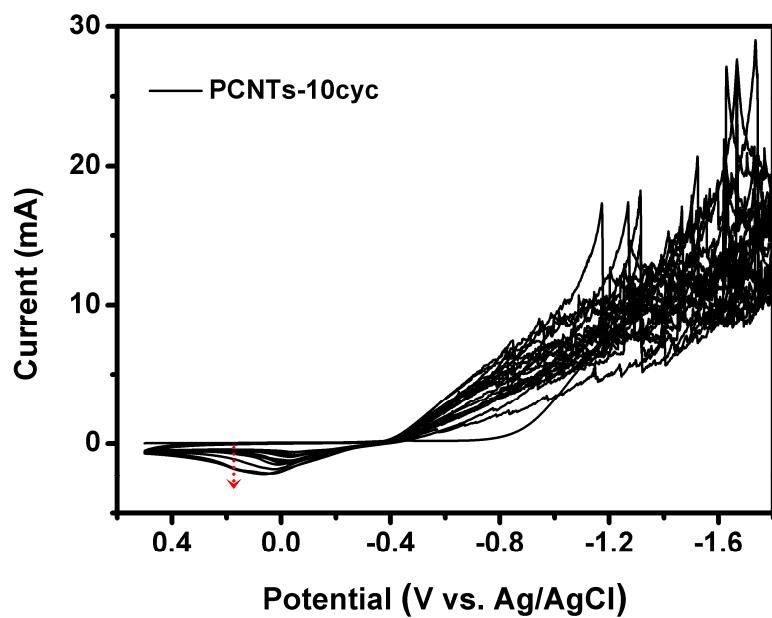
### **Neuron-Inspired Interpenetrative Network Composed of Cobalt-Phosphorus-Derived Nanoparticles Embedded within Porous Carbon Nanotubes for Efficient Hydrogen Production**

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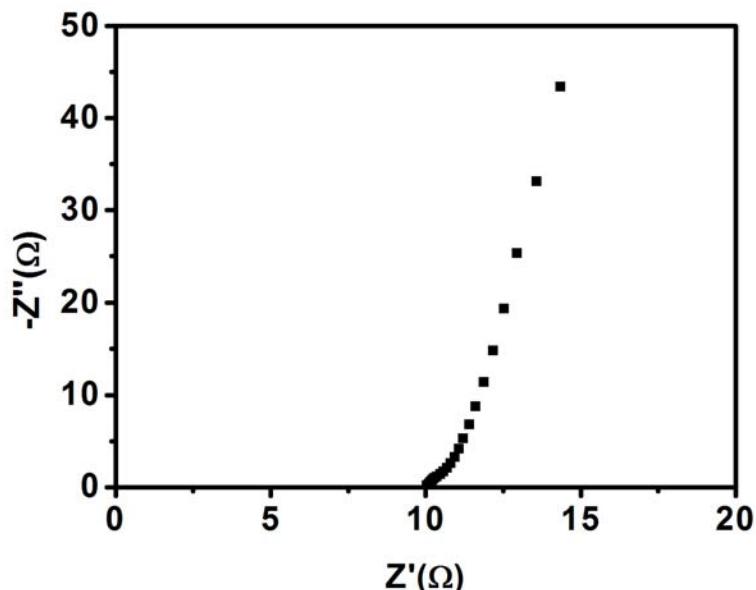
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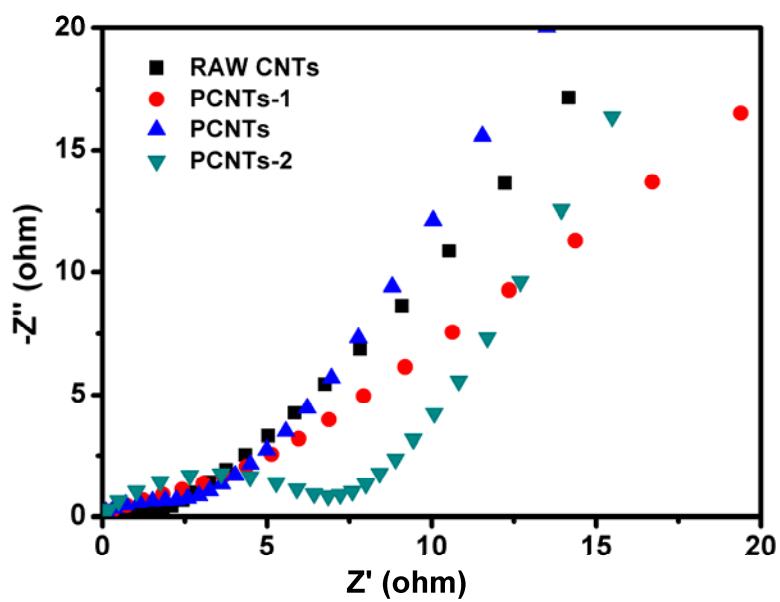
**Figure S1.** The entire CV curves during the formation of the PCNT-10cyc sample

## S2 Ohmic drop correction

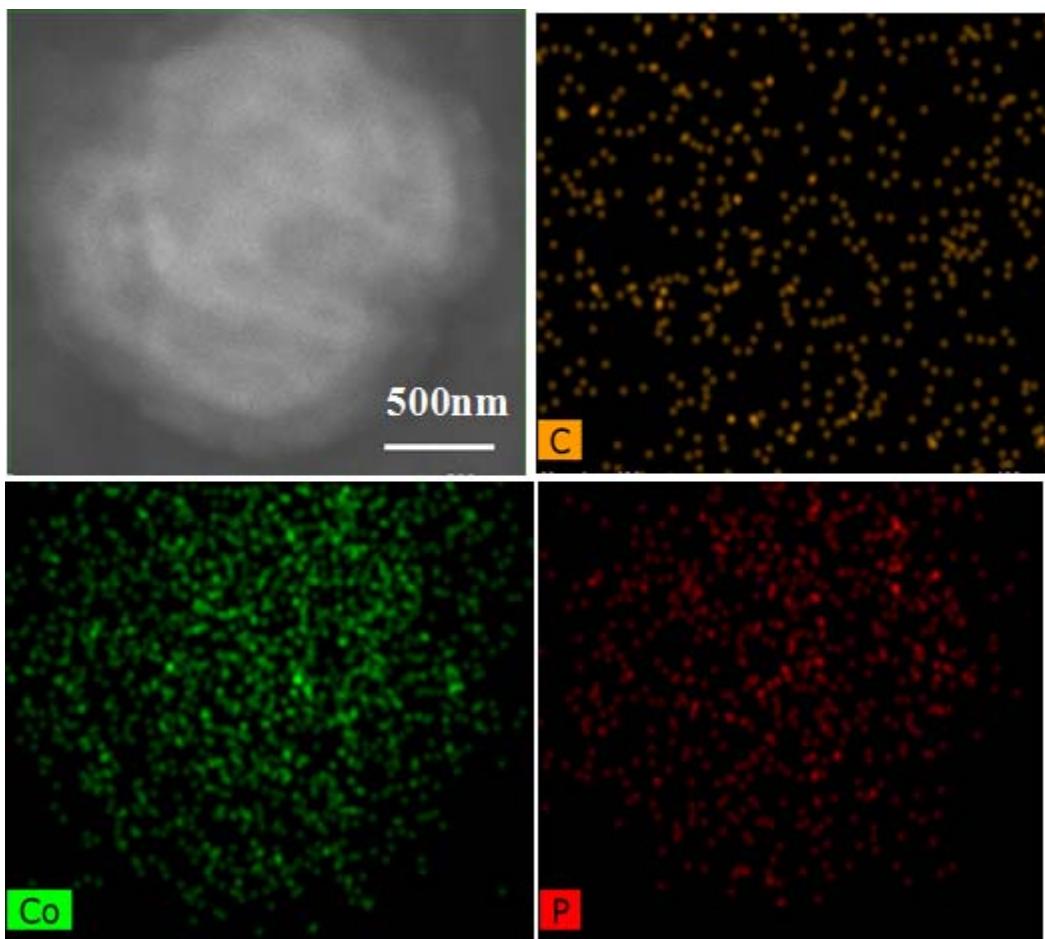
The ohmic drop correction was performed with a series resistance ( $R_s$ ) determined by electrochemical impedance measurement. The electrochemical impedance spectroscopy was performed from 100 kHz to 10 mHz at an open circuit voltage of 30 mV. In a type example, the resistance of the PCNTs-10cyc sample was determined to be  $\sim 9.9 \Omega$ , as shown in the Nyquist plot of Fig. S2. The  $iR$  correction to data with the series resistance is done by the equation of  $\eta_{\text{corr}} = \eta_{\text{exp}} - iR$ .



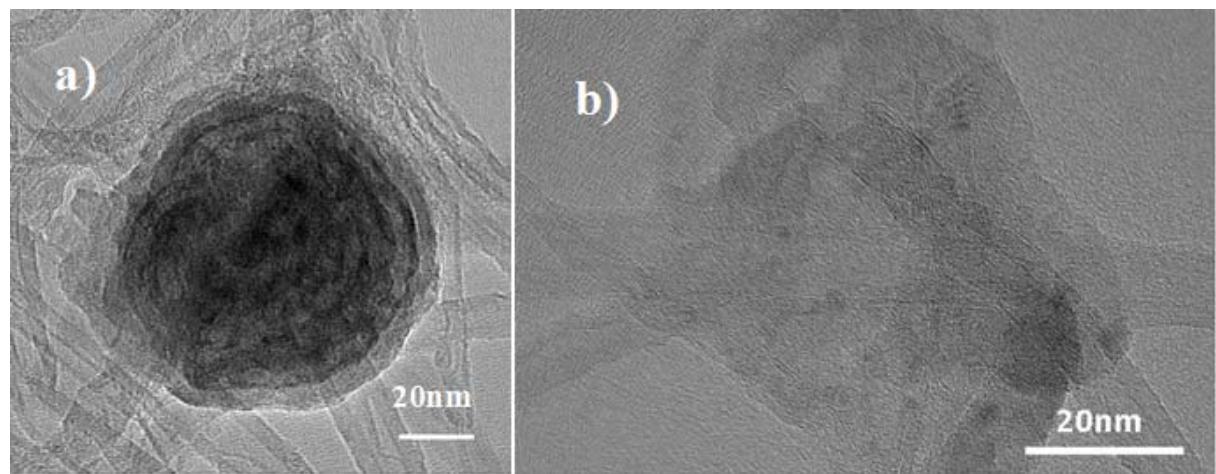
**Figure S2.** Nyquist plot of the PCNTs-10cyc sample.



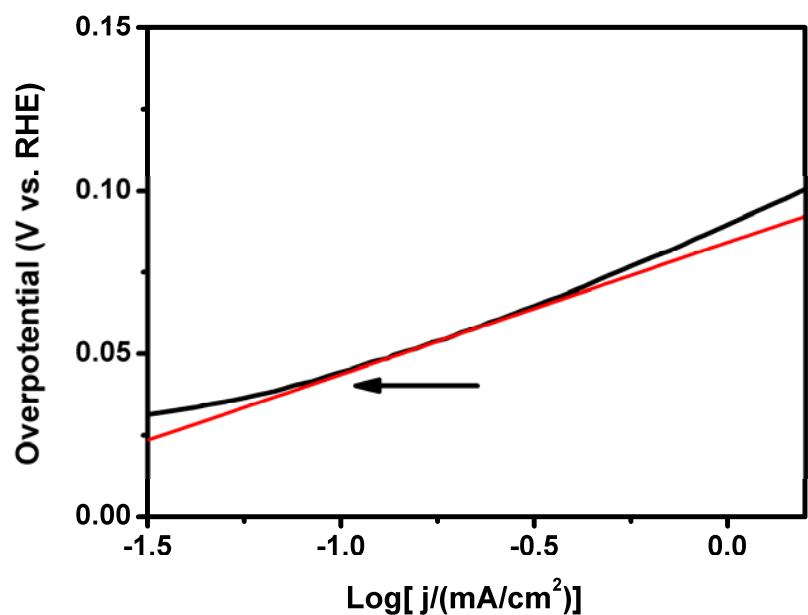
**Figure S3.** Electrochemical impedance spectra of raw CNTs and PCNTs.



**Figure S4.** STEM and corresponding element mapping of PCNTs-50cyc.



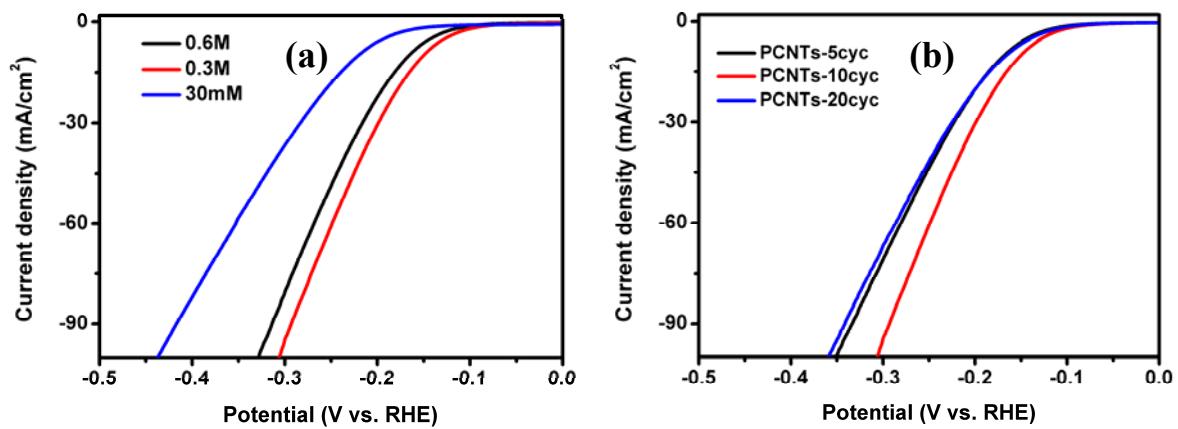
**Figure S5.** Enlarged TEM image of PCNTs-10cyc.



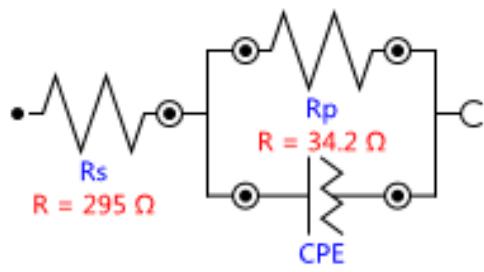
**Figure S6.** Tafel plot in the region of low current densities of PCNTs-10cyc in 0.5 M H<sub>2</sub>SO<sub>4</sub>. The onset overpotential is determined by the potential when the plot starts to deviate from the linear region as indicated by the arrow.

**Table S1.** Comparison of HER performance in acid media for NIN-Co-P/PCNTs nanocomposites with other HER electrocatalysts. (<sup>a</sup> catalysts directly grown on current collectors)

Catalyst	Onset potential (mV)	Tafel slope (mV/dec)	Current density (j, mA/cm <sup>2</sup> )	η at the corresponding j (mV)	Exchange current density (mA/cm <sup>2</sup> )	TOF(s <sup>-1</sup> )	Ref.
NIN-Co-P/PCNTs	43	40	2	99.5			
			10	150.6			
			20	177.6	$1.0 \times 10^{-2}$	$3.2 \eta=0.2\text{V}$	This work
CoP-n <sup>+</sup> Si		61	10	202	$6.60 \times 10^{-3}$	$0.48 \eta=0.1\text{V}$ $1.0 \eta=0.12\text{V}$	[1]
CoP	100	76	10	226			
			20	275	$1.9 \times 10^{-2}$		[2]
Branched CoP nanostructures		48	20	117			
			60	145		$0.019 \eta=0.1\text{V}$	[3]
CoP NPs		87	10	221	$5.4 \times 10^{-2}$		[4]
Co <sub>2</sub> P nanorods	70	71	10	134			
			20	167		$0.725 \eta=0.143\text{V}$	[5]
CoP NTs		60	2	72			
			10	129			
			10	67		$1.0 \eta=0.106\text{V}$	[6]
CoP/CC	38	51	20	100			
			60	165	$0.288$	$0.725 \eta=0.075\text{V}$	[7]
CoP/Ti		50	20	95			[8]
Ni <sub>2</sub> P NPs	46		20	130			
			100	180	$3.3 \times 10^{-2}$	$0.50 \eta=0.2\text{V}$	[9]
Ni <sub>5</sub> P <sub>4</sub>		40	10	140			[10]
Ni <sub>2</sub> P	170	70	10	346	$3.84 \times 10^{-6}$	$0.025 \eta=0.1\text{V}$	[11]
MoP	50	54	30	180	0.034		[12]
Co@NC/NG	49	79.3	13.6	200			
			2	83			[13]
[Mo <sub>3</sub> S <sub>13</sub> ] <sup>2-</sup> cluster	100-200	40	10	180		$3.0 \eta=0.2\text{V}$	[14]
MoS <sub>3</sub> /FTO <sup>a</sup>	120	40	2	170			
			16	300	$1.3 \times 10^{-4}$	$0.8 \eta=0.22\text{V}$	[15]
Double-gyroid MoS <sub>2</sub> /FTO <sup>a</sup>	150-200	50	2	190	$6.9 \times 10^{-4}$		
							[16]
Defect-rich MoS <sub>2</sub>	120	50	13	200	$8.91 \times 10^{-3}$	$0.7 \eta=0.3\text{V}$	[17]
PI/CNT-RGO-MoS <sub>2</sub>	90	61	3	100			
			13	200	$1.1 \times 10^{-2}$		[18]
Nanostructured MoS <sub>2</sub> /CC	100	50	86	250	$9.2 \times 10^{-3}$		[19]
							[20]



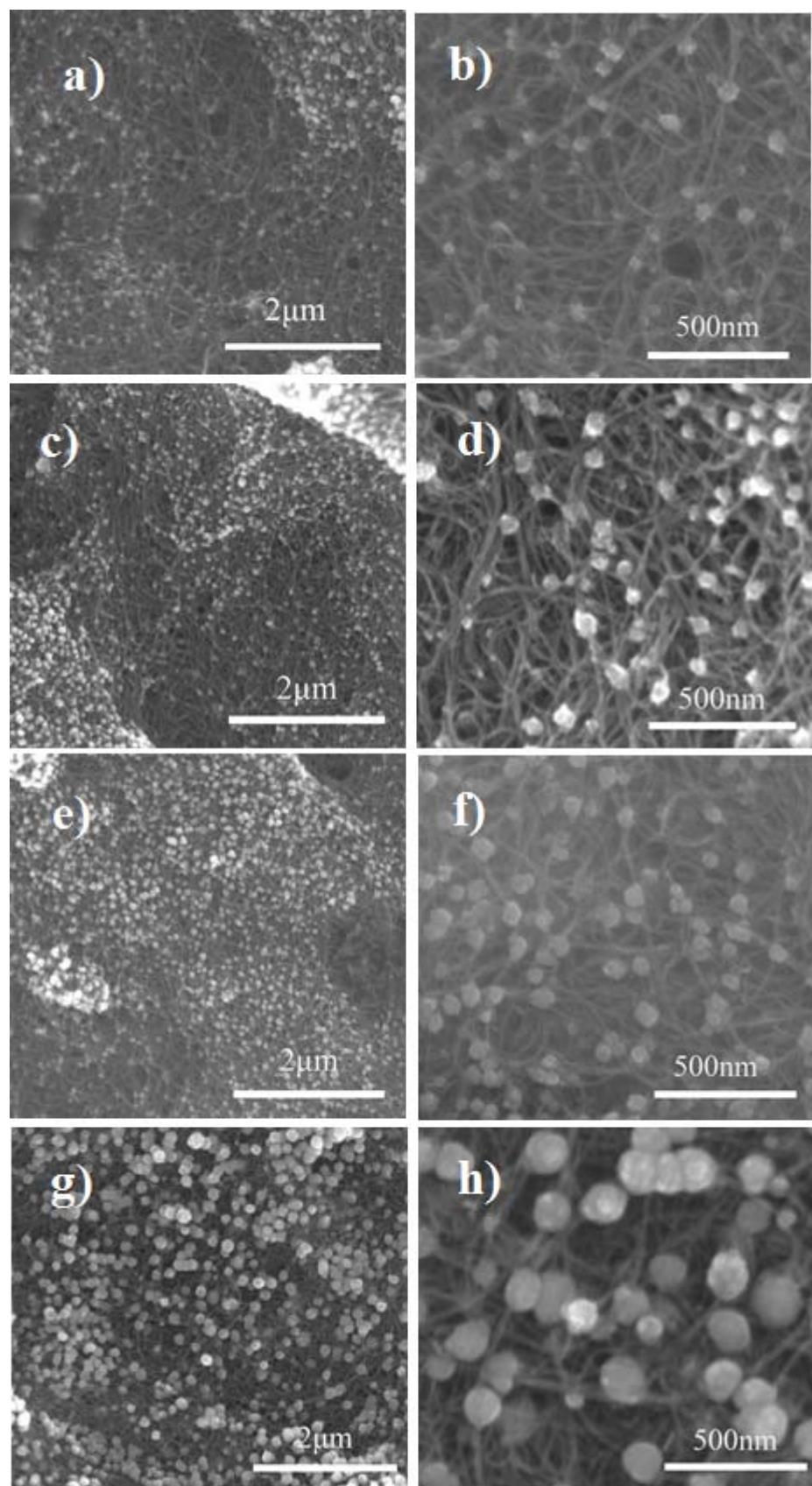
**Figure S7.** (a) polarization curves for the PCNT-10cyc samples under various precursor concentrations; (b) polarization curves for PCNTs-5cyc, PCNTs-10cyc, PCNTs-20cyc samples obtained in 0.3 M  $\text{CoSO}_4 \cdot 7\text{H}_2\text{O}$ , 0.3M  $\text{NaH}_2\text{PO}_2 \cdot \text{H}_2\text{O}$  solution containing 0.4 M  $\text{H}_3\text{BO}_3$ .



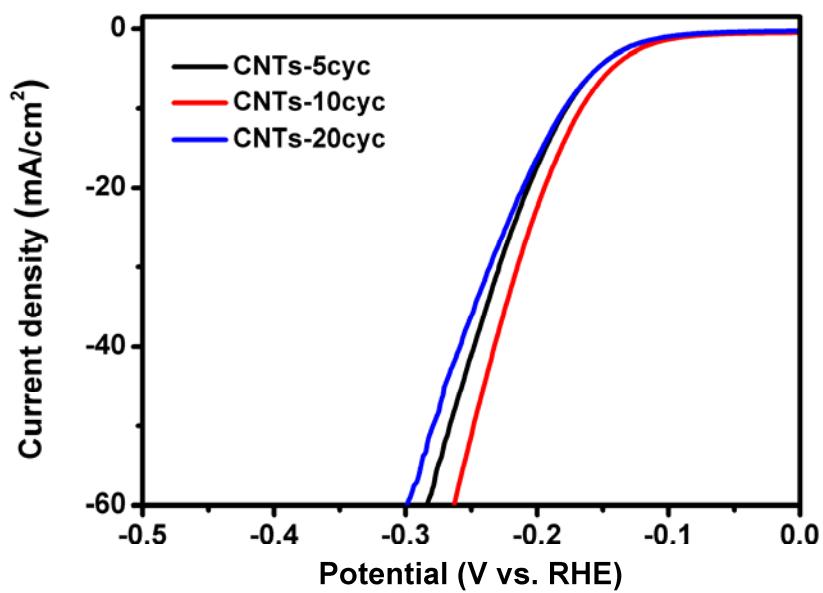
**Figure S8.** Their electrical equivalent circuit diagram for fitting the solid-liquid interface .

**Table S2.** The impedance parameters derived by fitting the EIS responses on the NIN-Co-P/PCNTs nanocomposites with various deposition cycles in 5 mM H<sub>2</sub>SO<sub>4</sub>.

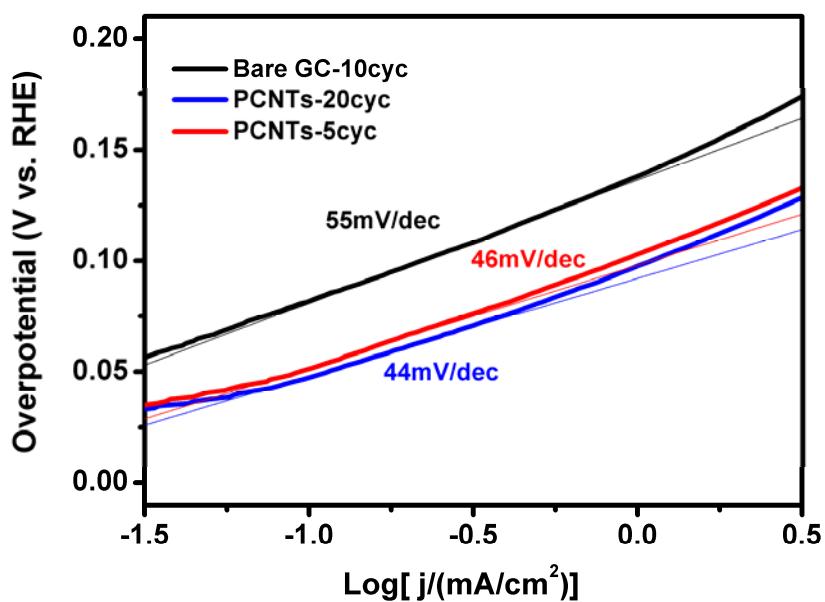
Samples	R <sub>S</sub> (Ω)	R <sub>P</sub> (Ω)	CPE (μMho)
PCNTs-5cyc	338	39.8	4.66
PCNTs-10cyc	295	34.2	67
PCNTs-20cyc	319	62	9.9



**Figure S9.** SEM images of (a,b) PCNTs-5cyc, (c,d) PCNTs-10cyc, (e,f) PCNTs-20cyc, (g,h) PCNTs-50cyc.



**Figure S10.** Polarization curves for CNTs-5cyc, CNTs-10cyc, CNTs-20cyc in  $\text{H}_2\text{SO}_4$  solution (0.5M).



**Figure S11.** Tafel plots of PCNTs-5cyc, PCNTs-20cyc and Bare GC-10cyc.

## S12 Estimation of Turn Over Frequency (TOF)

To estimate the turn over frequency (TOF) for the NIN-Co-P/PCNTs composites catalyst, we adopt the approach that used in Jaramillo et al<sup>[21, 22]</sup>. First, the potential was swept between 0.10 to 0.30 V vs RHE at each of five different scan rates (20, 40, 80, 160, 200 mV/s) to measure electrochemical capacitance. The cyclic voltammograms can be seen in Figures S11a. We measured the capacitive currents in a potential range where no faradic processes are observed, i.e. at 0.20 V vs RHE. The measured capacitive currents are plotted as a function of scan rate in Figure S11b and a linear fit determined the specific capacitance to be 8.22 mF/cm<sup>2</sup> for PCNTs-10cyc, and 7.61 mF/cm<sup>2</sup> for PCNTs. The specific capacitance can be converted into an electrochemical active surface area (ECSA) using the specific capacitance value for a flat standard with 1 cm<sup>2</sup> of real surface area. The specific capacitance for a flat surface is generally found to be in the range of 20-60 μF cm<sup>-2</sup><sup>22-26</sup>. In the following calculations of TOF we assume 40 μF cm<sup>-2</sup>.

Calculated electrochemical active surface area.

$$A_{ECSA}^{CoP} = \frac{Capacitance((PCNTs - 10cyc) - PCNTs)}{40 \mu F cm^{-2} per cm_{ECSA}^{-2}}$$

To further access the per-site TOF, we used following formula:

$$TOF \text{ per site} = \frac{\# \text{Total Hydrogen Turn Over / cm}^2 \text{ geometric area}}{\# \text{Surface Sites(Catalyst) / cm}^2 \text{ geometric area}}$$

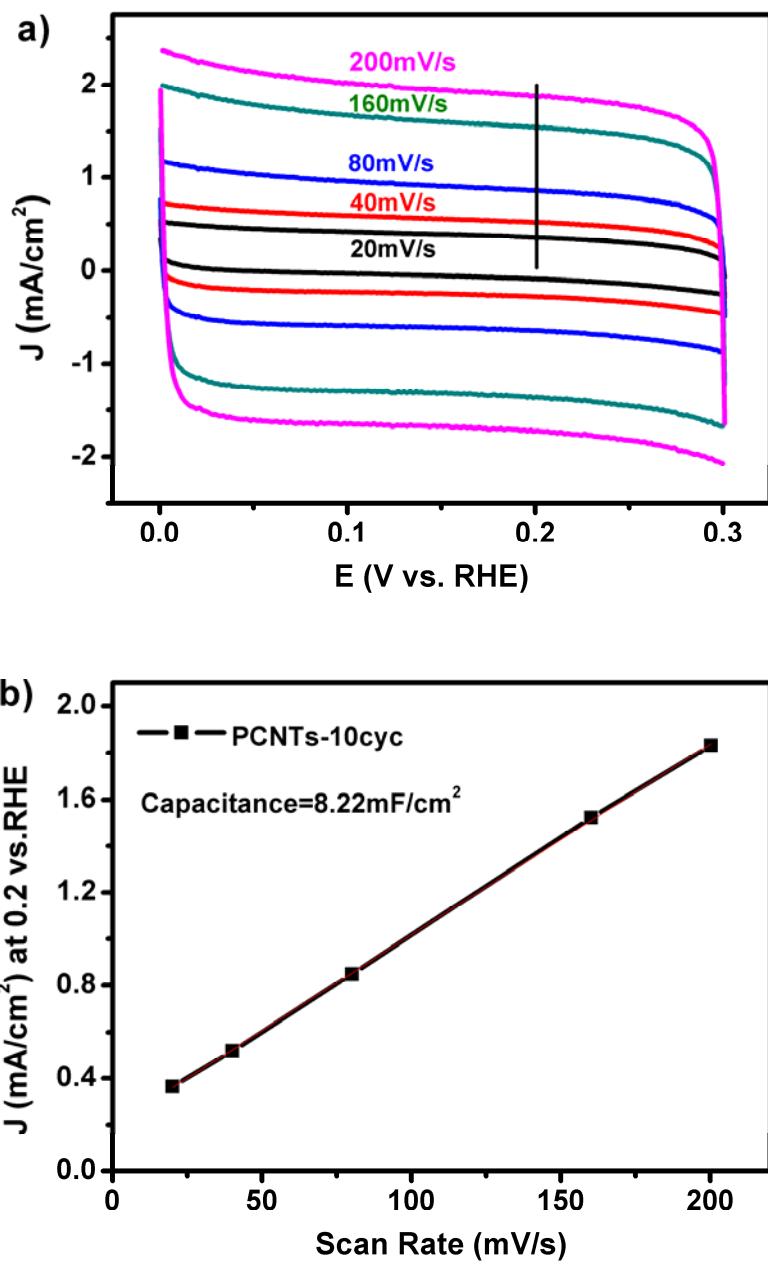
# Surface sites per real surface area

$$\text{Surface sites} = 1.948 * 10^{15} \text{ atoms cm}^{-2}_{\text{real}} \quad ^{26}$$

Total number of hydrogen turn over events per geometric area happened at 1mA/cm<sup>2</sup> close to  $3.12 \times 10^{15} \frac{H_2 / s}{cm^2}$ .<sup>26</sup>

So the TOF per site at η = 0.2V (current density of 30.28 mA/cm<sup>2</sup>) and pH = 0 is determined as follows.

$$\frac{\left(3.12 \times 10^{15} \frac{H_2 / s}{cm^2} per \frac{mA}{cm^2}\right) \times \left(30.28 \frac{mA}{cm^2}\right)}{surface \text{ sites} \times A_{ECSA}} = 3.2 \frac{H_2 / s}{surface \text{ sites}}$$



**Figure S12.** (a) Cyclic voltammetry curves of PCNTs-10cyc in the region of 0-0.3V vs RHE. (b) The differences in current density variation at an overpotential of 0.2V plotted against scan rate fitted to a linear regression enables the estimation of double-layer capacitance.

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